

Calculation of the Linear-Absorption Spectrum of an Ideal Two-Dimensional System of MoS_2

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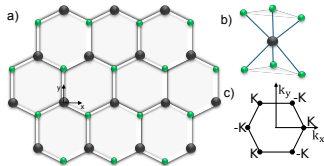
June 23, 2024

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Transition Metal Dichalcogenides Monolayer

Group VI-B Transition Metal Dichalcogenides (TMD) are compound semiconductors of the type MX_2 . M is Transition Metal atom (black dots), X are Dichalcogenides atom (green dots):



- They are stable in both mono- and few-layer in the air at room temperature.
- They are semiconductor with a direct band gap.
- Strong spin-orbit Coupling (SOC) in TMD monolayers leads to spin splitting of hundreds meV.

Exciton Binding Energy In TMD

Why calculate the linear absorption spectrum?

→ Exciton Binding Energy

- TMD is a low-dimension material, create huge binding energy in compare with bulk semiconductor → huge effect on phenomenon ⇒ need to be calculated and taken into account in any further many-body calculation.
- Early theories predict binding energy too large (0.5 – 1 eV) in compare with experiment (0.2 – 0.5 eV) ⇒ need precise calculation in agree with experiment.
- Other theory only fitting bandstructure around high symmetry point such as K/K' , not on entire BZ ⇒ Tight-Binding method for fitting on entire BZ.

Three-band Tight-binding Model

Tight-Binding (TB) wave function have the form of Linear combination of Atomic Orbital (LCAO):

$$|\psi_{\lambda\mathbf{k}}(\mathbf{r})\rangle = \sum_{\alpha} c_{\lambda\alpha}(\mathbf{k}) \sum_{\mathbf{R}} e^{i\mathbf{k}\mathbf{R}} |\phi_{\alpha}(\mathbf{r} - \mathbf{R})\rangle \quad (1)$$

Time-independence independence-electron approximation Schrödinger equation with LCAO included:

$$H_{1e} \sum_{\alpha} c_{\lambda\alpha}(\mathbf{k}) \sum_{\mathbf{R}} e^{i\mathbf{k}\mathbf{R}} |\phi_{\alpha}(\mathbf{r} - \mathbf{R})\rangle = \varepsilon_{\lambda}(\mathbf{k}) \sum_{\alpha} c_{\lambda\alpha}(\mathbf{k}) \sum_{\mathbf{R}} e^{i\mathbf{k}\mathbf{R}} |\phi_{\alpha}(\mathbf{r} - \mathbf{R})\rangle$$

Multiply with $\langle\phi_{\beta}|$ on the left and take integral over \mathbf{r}

$$\sum_{\alpha} [H_{\beta\alpha}^{TB}(\mathbf{k}) - \varepsilon_{\lambda}(\mathbf{k})\delta_{\beta\alpha}] c_{\lambda\alpha}(\mathbf{k}) = 0. \quad (2)$$

In which the Tight-binding Hamiltonian matrix elements:

$$H_{\beta\alpha}^{TB}(\mathbf{k}) = \sum_{\mathbf{R}} \langle\phi_{\beta}(\mathbf{r})| H_{1e} |\phi_{\alpha}(\mathbf{r} - \mathbf{R})\rangle \quad (3)$$

Three-band Tight-binding Model

Use basic functions of d-type Orbitals:

$$|\phi_1\rangle = d_{z^2}, |\phi_2\rangle = d_{xy}, |\phi_3\rangle = d_{x^2-y^2}.$$

Three-band TB Hamiltonian with SOC has the form:

$$H_{6 \times 6}^{TB}(\mathbf{k}) = \begin{bmatrix} H_{3 \times 3}^{TB}(\mathbf{k}) + \gamma L_z & 0 \\ 0 & H_{3 \times 3}^{TB}(\mathbf{k}) - \gamma L_z \end{bmatrix}, \quad L_z = \begin{bmatrix} 0 & 0 & 0 \\ 0 & 0 & i \\ 0 & -i & 0 \end{bmatrix} \quad (4)$$

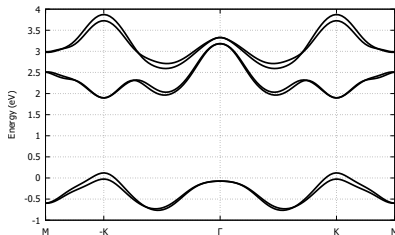


Figure: MoS_2 Bandstructure calculated from 3-band TB models¹

Multiband velocity gauge semiconductor Bloch equations (SBE) with Coulomb interaction in Hatree Fock approximation:

$$\begin{aligned} \frac{d}{dt} \rho_{\lambda\lambda'}(\mathbf{k}, t) = & -\frac{i}{\hbar} (\varepsilon_{\lambda}(\mathbf{k}) - \varepsilon_{\lambda'}(\mathbf{k})) \rho_{\lambda\lambda'}(\mathbf{k}) \\ & - i \sum_{\mu} (\Omega_{\lambda\mu}(\mathbf{k}) \rho_{\mu\lambda'}(\mathbf{k}, t) - \rho_{\lambda\mu}(\mathbf{k}, t) \Omega_{\mu\lambda'}(\mathbf{k})) \\ & + \frac{\rho_{\lambda\lambda'}(\mathbf{k}, t)}{T_2} (1 - \delta_{\lambda\lambda'}), \end{aligned} \quad (5)$$

where

$$\Omega_{\mu\nu}(\mathbf{k}) = \frac{1}{\hbar} \left(\frac{e}{m} \mathbf{A}(t) \mathbf{p}_{\mu\nu}(\mathbf{k}) - \sum_{\alpha\beta\mathbf{q}} W_{\mathbf{k},\mathbf{k}+\mathbf{q},\mathbf{q}}^{\alpha\mu\beta\nu} \rho_{\beta\alpha}(\mathbf{k} + \mathbf{q}) \right), \quad (6)$$

$$\mathbf{p}_{\mu\nu}(\mathbf{k}) = \frac{m}{\hbar} \sum_{\alpha,\beta} c_{\mu\alpha}^* \nabla_{\mathbf{k}} H_{\alpha\beta}^{TB}(\mathbf{k}) c_{\nu\beta}(\mathbf{k}) \quad (7)$$

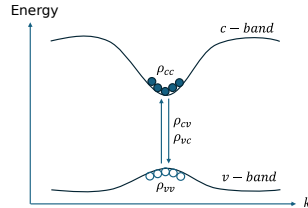
Inter-band Polarization

For $\mu \neq \nu$:

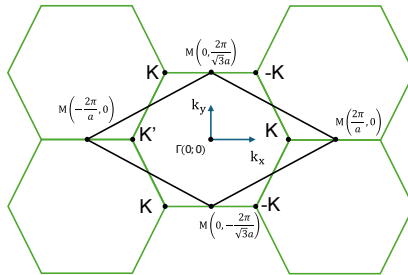
$$\vec{\xi}_{\mu\nu}(\mathbf{k}) = \frac{-i\hbar}{m} \frac{\mathbf{p}_{\mu\nu}(\mathbf{k})}{\varepsilon_{\mu}(\mathbf{k}) - \varepsilon_{\nu}(\mathbf{k})} \quad (8)$$

Time-dependence interband polarization density:

$$\begin{aligned} \mathbf{P}(t) &= \frac{e}{L^2} \sum_{\mathbf{k}} \text{Tr} \left[\vec{\xi}(\mathbf{k}) \rho(\mathbf{k}, t) \right] \\ &= \frac{e}{L^2} \sum_{\mathbf{k} \lambda \lambda'} \vec{\xi}_{\lambda \lambda'}(\mathbf{k}) \rho_{\lambda' \lambda}(\mathbf{k}, t) \end{aligned} \quad (9)$$

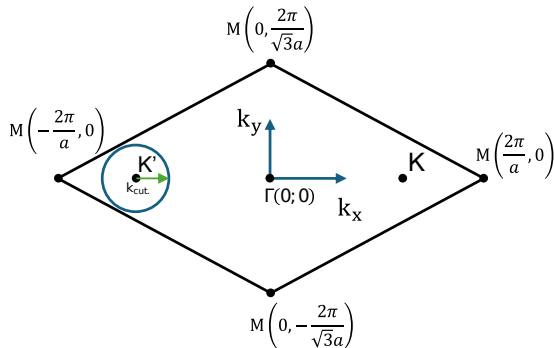


Numerical Sum Over k-Space



$$\sum_{\mathbf{k}} \dots \rightarrow \frac{L^2}{4\pi^2} \int \int_{BZ} dk_x dk_y \dots \quad (10)$$

k-Cutoff



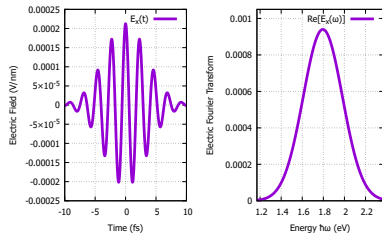
$$W_{\mathbf{k}, \mathbf{k}', \mathbf{q}}^{\alpha\mu\beta\nu} \approx W_{\mathbf{k}, \mathbf{k}', \mathbf{q}}^{\alpha\mu\beta\nu} \theta(k_{cut.} - |\mathbf{k} - \mathbf{k}_{K'}|) \theta(k_{cut.} - |\mathbf{k}' - \mathbf{k}_{K'}|). \quad (11)$$

Electromagnetic Field

Electromagnetic has Gaussian form:

$$\mathbf{E}(t) = \mathbf{E}_0 \cos(\omega t) e^{-\frac{t^2}{\tau_L^2}} \quad (12)$$

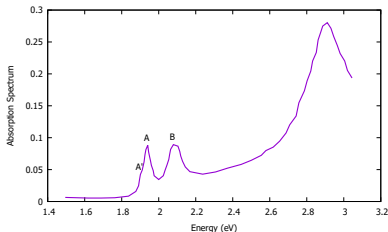
- small $E_0 : \rho_{cc}(\mathbf{k}) \rightarrow 0$
- $\hbar\omega = E_{gap.} \rightarrow$ linear absorption
- small τ_L for better range around ω



Absorption obtain by²:

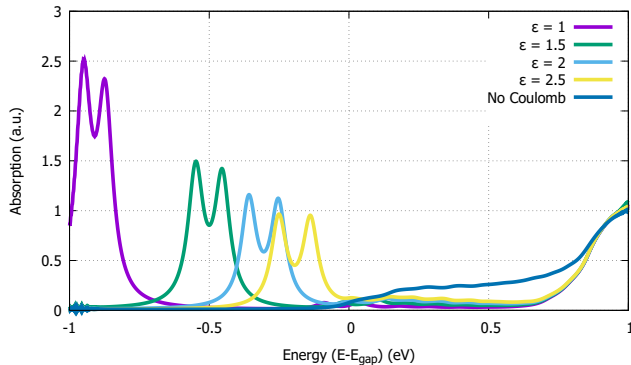
$$\alpha(\omega) \propto \frac{P(\omega)}{E(\omega)} \quad (13)$$

Experiment measure:

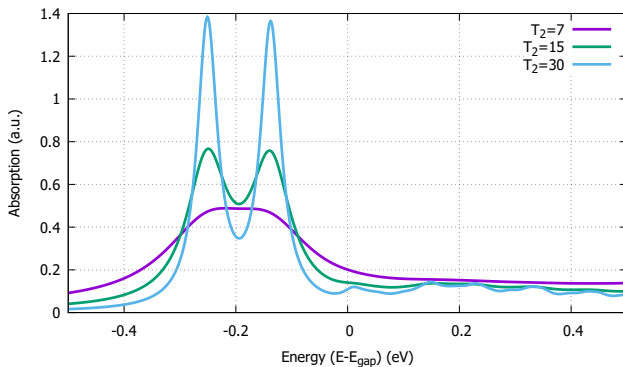


- Two resonance labeled by A and B is Exciton peak. Show band split by SOC
- Small trion peak near A label by A'

Figure: Measure Absorption Spectrum of MoS₂ at $T = 5K$ extracted from³



- Choosing the ϵ for fitting with experiment.
- For 3-band TB model: $\epsilon \in (1.5, 2.5)$ is good with Exciton binding energy $E_{\text{bind.}} = 0.2 - 0.5 \text{ eV}$



- Choosing the T_2 for clearer Exciton peak.
- The bigger T_2 , the clearer main Exciton peaks \rightarrow confirm.
- At $T_2 = 30fs$ show other smaller exciton peaks \rightarrow predict.

Summary:

- From three-band TB + SBE \rightarrow Linear Absorption Spectrum
- Confirm on Exciton binding energy in monolayer MoS_2 in contract with experiment, predict smaller exciton peaks.

Further research:

- High Harmonic Generation
- High-order Side-band Generation
- Photovoltaic effect

- [1] G.-B. Liu, W.-Y. Shan, Y. Yao, W. Yao, and D. Xiao, “Three-band tight-binding model for monolayers of group-VIB transition metal dichalcogenides,” *Physical Review B*, vol. 88, p. 085433, Aug. 2013. Publisher: American Physical Society.
- [2] H. Haug and S. W. Koch, *Quantum Theory Of The Optical And Electronic Properties Of Semiconductors (5th Edition)*. World Scientific Publishing Company, Jan. 2009. Google-Books-ID: 1J1IDQAAQBAJ.
- [3] C. Zhang, H. Wang, W. Chan, C. Manolatou, and F. Rana, “Absorption of light by excitons and trions in monolayers of metal dichalcogenide MoS_2 : Experiments and theory,” *Physical Review B*, vol. 89, p. 205436, May 2014. Publisher: American Physical Society.